

L Number	Hits	Search Text	DB	Time stamp
1	23	((trench\$2 groove\$3 window\$2 recess\$2)near2( sige silicon near2 germanium))same(compris\$4 form\$4 depos\$4 fill\$4 dislocation\$4 defect\$4) and (lithograph\$4 etch\$4) and emitter and (H01L029/70 H01L029/732 H01L029/737.ipc. H01L031/0328 H01L031/328 H01L031/336.ipc.)	USPAT; US-PGPUB	2004/03/24 12:45
2	11	((trench\$2 groove\$3 window\$2 recess\$2)and( sige silicon near2 germanium))and(compris\$4 form\$4 depos\$4 fill\$4 dislocation\$4 defect\$4 facet\$2))and (lithograph\$4 etch\$4) and emitter and (H01L029/70 H01L029/732 H01L029/737.ipc. H01L031/0328 H01L031/328 H01L031/336.ipc.)	EPO; JPO; DERWENT	2004/03/24 12:46
-	59	(( sige silicon near2 germanium)ncar33( non\$1recess\$4 recess\$2))	USPAT; US-PGPUB	2004/03/24 12:44
-	5180	(( sige silicon near2 germanium)near13(fill\$3 deposit\$3 form\$4))	USPAT; US-PGPUB	2004/03/15 22:56
-	124	(( sige sige silicon near2 germanium)near21(corner\$4 edg\$2))	USPAT; US-PGPUB	2004/03/15 22:56
-	8	(((( sige silicon near2 germanium)near33( non\$1recess\$4 recess\$2)) ) and ((( sige silicon near2 germanium)near13(fill\$3 deposit\$3 form\$4)) ) and ( (( sige sige silicon near2 germanium)near21(corner\$4 edg\$2))))	USPAT; US-PGPUB	2004/03/15 22:52
-	8	(((( sige silicon near2 germanium)near33( non\$1recess\$4 recess\$2)) ) and ( (( sige sige silicon near2 germanium)near21(corner\$4 edg\$2))))	USPAT; US-PGPUB	2004/03/15 22:51
-	45	(((( sige silicon near2 germanium)near33( non\$1recess\$4 recess\$2)) ) and ((( sige silicon near2 germanium)near13(fill\$3 deposit\$3 form\$4)) )	USPAT; US-PGPUB	2004/03/15 22:51
-	80	(((( sige silicon near2 germanium)near13(fill\$3 deposit\$3 form\$4)) ) and ( (( sige sige silicon near2 germanium)near21(corner\$4 edg\$2))))	USPAT; US-PGPUB	2004/03/15 22:52
-	72	(( ((( sige silicon near2 germanium)near13(fill\$3 deposit\$3 form\$4)) ) and ( (( sige sige silicon near2 germanium)near21(corner\$4 edg\$2)))) not ((((( sige silicon near2 germanium)near33( non\$1recess\$4 recess\$2)) ) and ((( sige silicon near2 germanium)near13(fill\$3 deposit\$3 form\$4)) ))	USPAT; US-PGPUB	2004/03/15 22:52
-	57	(( sige silicon near2 germanium)and( non\$1recess\$4 recess\$2))	EPO; JPO; DERWENT	2004/03/15 22:56
-	20297	(( sige silicon near2 germanium)and(fill\$3 deposit\$3 form\$4))	USPAT; US-PGPUB	2004/03/15 22:57
-	120	(( sige sige silicon near2 germanium)and(corner\$4 edg\$2))	EPO; JPO; DERWENT	2004/03/15 22:57
-	4276	(( sige silicon near2 germanium)and(fill\$3 deposit\$3 form\$4))	EPO; JPO; DERWENT	2004/03/15 22:57
-	8	(((( sige silicon near2 germanium)and( non\$1recess\$4 recess\$2)) ) and ( (( sige sige silicon near2 germanium)and(corner\$4 edg\$2))) and ((( sige silicon near2 germanium)and(fill\$3 deposit\$3 form\$4)) )	EPO; JPO; DERWENT	2004/03/15 22:57
-	129	((trench\$2 groove\$3 window\$2)near21( sige silicon near2 germanium))same(compris\$4 form\$4 depos\$4 fill\$4 dislocation\$4 defect\$4) and (lithograph\$4 etch\$4) and emitter	USPAT; US-PGPUB	2004/03/23 19:46
-	8	((trench\$2 groove\$3 window\$2)near21( sige silicon near2 germanium))same(facet edge\$2 corner\$2)) and (lithograph\$4 etch\$4) and emitter	USPAT; US-PGPUB	2004/03/23 19:48
-	10	((opening\$2)near21( sige silicon near2 germanium))same(facet edge\$2 corner\$2)) and (lithograph\$4 etch\$4) and emitter	USPAT; US-PGPUB	2004/03/23 19:50
-	2	((opening\$2)and( sige silicon near2 germanium))and(facet edge\$2 corner\$2)) and (lithograph\$4 etch\$4) and emitter	EPO; JPO; DERWENT	2004/03/23 19:51
-	16	((trench\$2 groove\$3 window\$2)near21( sige silicon near2 germanium))and(compris\$4 form\$4 depos\$4 fill\$4 dislocation\$4 defect\$4 facet\$2))and (lithograph\$4 etch\$4) and emitter	EPO; JPO; DERWENT	2004/03/23 19:55
-	4	((trench\$2 groove\$3 window\$2)near21( sige silicon near2 germanium))and(edge\$2 corner\$2))and (lithograph\$4 etch\$4) and emitter	EPO; JPO; DERWENT	2004/03/23 19:55